



PATENT APPLICATION
Docket No. 9898-321
Client No. SS-18146-US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Ki-Yeon PARK, et al.

Serial No. 10/713,577 Examiner: Nhu, David

Filed: November 12, 2003 Group Art Unit: 2818

Confirmation No. 8248

For: CAPACITOR OF SEMICONDUCTOR MEMORY DEVICE THAT
HAS COMPOSITE $\text{Al}_2\text{O}_3/\text{HfO}_2$ DIELECTRIC LAYER AND
METHOD OF MANUFACTURING THE SAME

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

RESPONSE TO RESTRICTION REQUIREMENT

Responsive to the Restriction Requirement, dated October 13, 2004, Applicant hereby
elects Group II (claims 16-27), without traverse.

Customer No. 20575

Respectfully submitted,

MARGER JOHNSON & McCOLLOM, PC

Hosoon Lee
Limited Recognition Under 37 CFR § 10.9(b)

1030 SW Morrison Street
Portland, OR 97205
(503) 222-3613

I hereby certify that this correspondence
is being deposited with the United States
Postal Service as first class mail in an
envelope addressed to: Commissioner for
Patents, P.O. Box 1450, Alexandria, VA
22313-1450
Date: November 15, 2004

Li Mei Vermilya